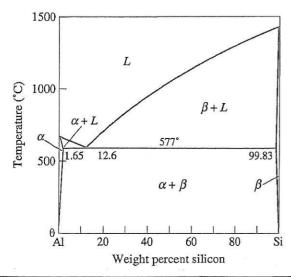
國立東華大學招生考試試題第_/頁,共2頁

-					_	-		-		
招	生。	學 年	度	104	招	生	類	別	碩士班	
系	所	班	别	材料科學與工程學系碩士班						
科	目	名	稱	材料科學導論						
注	意	事	項	本考科可使用掌上型計算機	83				B 8	

- 1. Beryllium has a hexagonal crystal structure, with a_0 =0.22858 nm and c_0 =0.35842 nm. The atomic radius is 0.1143 nm, the density is 1.848 g/cm³, and the atomic weight is 9.01 g/mol.
 - (a) Determine the number of atoms in each unit cell. (5%)
 - (b) Calculate the packing factor in the unit cell. (5%)
- 2. The metal rubidium has a BCC crystal structure. If the angle of diffraction for the (321) set of planes occurs at 27.00° (first-order reflection) when monochromatic x-radiation having a wavelength of 0.071 nm is used,
 - (a) Compute the interplanar spacing for this set of planes. (5%)
 - (b) Compute the atomic radius for the rubidium atom. (5%)
- 3. (a) Briefly explain why fine pearlite is harder and stronger than coarse pearlite, which in turn is harder and stronger than spheroidite. (7%)
 - (b) Briefly explain why the hardness of tempered martensite diminishes with tempering time and with increasing temperature. (8%)
- 4. Consider an Al-4% Si alloy (see the Al-Si phase diagram as below). Determine
 - (a) the amounts and compositions of each phase at 578°C. (5%)
 - (b) the amounts and compositions of each phase at 576°C. (5%)
 - (c) the amounts and compositions of each phase at 25°C. (5%)



國立東華大學招生考試試題第2頁,共2頁

招	生生	學 年	度	104	招	生	類	別	碩士班
系	所	班	別	材料科學與工程學系碩士班					
科	目	名	稱	材料科學導論					
注	意	事	項	本考科可使用掌上型計算機			81		

- 5. (a) Briefly explain the three steps of creep with a creep curve. (5%)
 - (b) Why recovery and strain hardening are important process during secondary creep stage. (5%)
 - (c) What are the factors affect the creep characteristics of metals. (5%)
 - (d) What is an ideal grain structure for creep-resistant alloy and why. (5%)
- 6. Please explain the following terms: (30%)
 - (a) Recrystallization temperature
 - (b) Stacking fault
 - (c) Activation energy
 - (d) Normalizing
 - (e) Coherent precipitates
 - (f) Sensitization